

D-Band Power Amplifier, 110 to 150 GHz, 15 dB Gain, 10 dBm P_{1dB}

Description:

Model SBP-1141541510-0606-E1 is a D-band power amplifier with a typical small signal gain of 15 dB and a typical P_{1dB} of 10 dBm across the frequency range of 110 to 150 GHz. The DC power requirement for the amplifier is +8 V_{DC}/300 mA. The input and output port configuration offers an inline structure with WR-06 waveguides and UG-387/U-M anti-cocking flanges. Other port configurations are available under different model numbers.



Features:

- High Gain and Output Power

Applications:

- Test Equipment
- Communication Systems
- Radar Systems

Electrical Specifications:

Parameter	Minimum	Typical	Maximum
Frequency	110 GHz		150 GHz
Gain		15 dB	
P _{1dB}		10 dBm	
P _{sat}		12 dBm	
P _{in}			12 dBm
Input Return Loss		8 dB	
Output Return Loss		5 dB	
DC Voltage		+8 V _{DC}	+12 V _{DC}
DC Supply Current		300 mA	
Specification Temperature		+25 °C	
Operating Temperature	0 °C		+50 °C

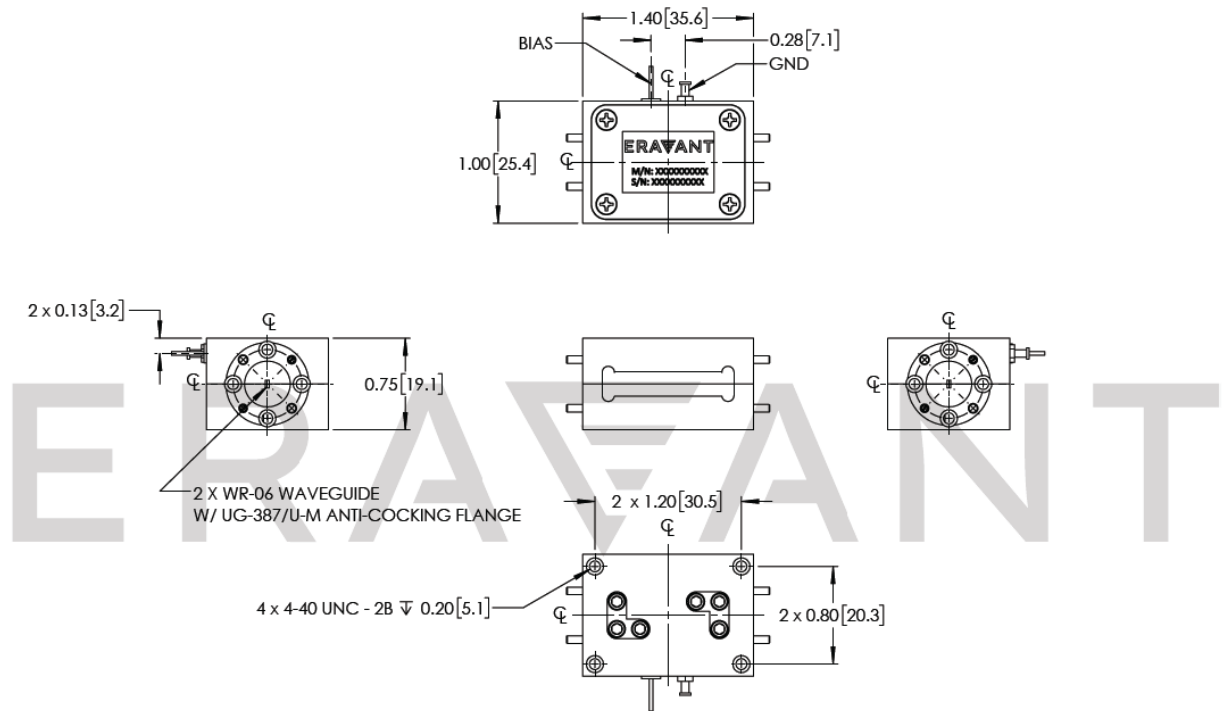
Mechanical Specifications:

Item	Specification
Input	WR-06 Waveguide with UG-387/U-M Anti-Cocking Flange
Output	WR-06 Waveguide with UG-387/U-M Anti-Cocking Flange
Bias	Solder Pin
Case Material	Aluminum
Finish	Gold Plated
Weight	1.6 Oz
Size	1.40" (L) X 1.00" (W) X 0.75" (H)
Outline	BG-SD-2-A



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Mechanical Outline: (Unless otherwise specified, all dimensions are in inches [millimeters])



Note:

- All data presented is collected from a sample lot. Actual data may vary unit to unit.
- All testing was performed under +25 °C case temperature.
- SAGE Millimeter, Inc. reserves the right to change the information presented without notice.

Caution:

- Exceeding absolute maximum ratings shown will damage the device.
- The device is static sensitive. Always follow ESD rules when working with the device.
- The case temperature of the device shall never exceed +50 °C. Use proper heatsink or fan if necessary.

